EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2888	257/691	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 15:54
L2	3520	257/692	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 16:03
L3	2218	257/693	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 16:09
L4	280	257/694	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 16:12
L5	331	257/695	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 16:19
L6	1366	257/696	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 17:08
L7	1371	257/697	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 17:10
L8	3504	257/698	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 17:26
L9	305	257/699	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 17:44
L10	3519	257/700	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 17:50

L11	160	257/e23.002	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2008/12/12 18:01
L12	6	semiconductor adj device and external and electrode and unequal and offset. clm.	US-PGPUB	OR	ON	2008/12/12 18:42
L13	140	semiconductor adj device and external and electrode and unequal and offset	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/12 18:43

12/12/08 6:56:27 PM